



HIGH-SIDE AND LOW-SIDE GATE DRIVER IN SO-8

Description

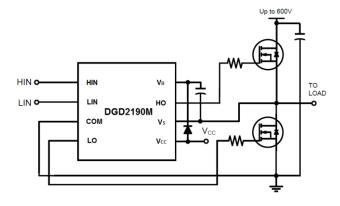
The DGD2190M is a high-voltage/high-speed gate driver capable of driving N-Channel MOSFETs and IGBTs in a half bridge configuration. High-voltage processing techniques enable the DGD2190M's high-side to switch to 600V in a bootstrap operation under high dV/dt conditions.

The DGD2190M logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) for easy interfacing with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction.

The DGD2190M is offered in the SO-8 package and operates over an extended -40°C to +125°C temperature range.

Applications

- DC-DC Converters
- DC-AC Inverters
- AC-DC Power Supplies
- Motor Controls
- Class D Power Amplifiers



Typical Configuration

Features

- Floating High-Side Driver in Bootstrap Operation to 600V
- Drives Two N-Channel MOSFETs or IGBTs in a Half-Bridge Configuation
- Output Drivers Capable of 4.5A/4.5A Typ. Sink/Source
- Logic Input (HIN and LIN) 3.3V Capability
- Schmitt Triggered Logic Inputs with Internal Pull-Down
- Undervoltage Lockout for High and Low-Side Drivers
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.
- https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SO-8 (Type TH)
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads,
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.075 grams (Approximate)



SO-8 Top View

Ordering Information (Note 4)

| Part Number | Marking | Reel Size (inches) | Tape Width (mm) | Quantity Per Reel |
|---------------|----------|--------------------|-----------------|-------------------|
| DGD2190MS8-13 | DGD2190M | 13 | 12 | 2,500 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

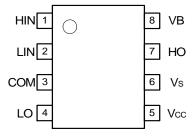
Marking Information



);; = Manufacturer's Marking
DGD2190M = Product Type Marking Code
YY = Year (ex: 19 = 2019)
WW = Week (01 to 53)



Pin Diagrams

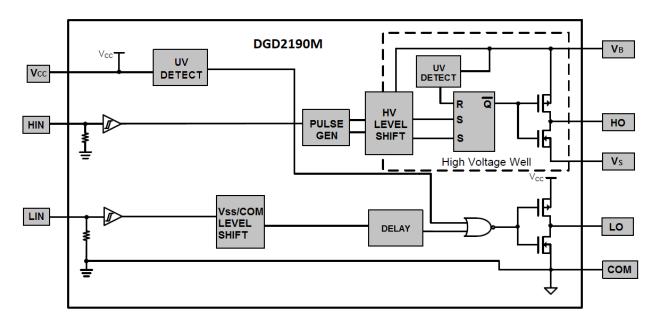


Top View: SO-8

Pin Descriptions

| Pin Number | Pin Name | Function | |
|------------|-----------------|--|--|
| 1 | HIN | Logic Input for High-side Gate Driver Output, in Phase with HO | |
| 2 | LIN | Logic Input for Low-side Gate Driver Output, in Phase with LO | |
| 3 | COM | Low-Side and Logic Return | |
| 4 | LO | Low-Side Gate Drive Output | |
| 5 | V _{CC} | Low-Side and Logic Fixed Supply | |
| 6 | Vs | High-Side Floating Supply Return | |
| 7 | НО | High-Side Gate Drive Output | |
| 8 | V _B | High-Side Floating Supply | |

Functional Block Diagram





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|----------------------|------------------------------|------|
| High-Side Floating Supply Voltage | V _B | -0.3 to +624 | V |
| High-Side Floating Supply Offset Voltage | Vs | V_B -24 to V_B +0.3 | V |
| High-Side Floating Output Voltage | V _{HO} | V_S -0.3 to V_B +0.3 | V |
| Offset Supply Voltage Transient | dV _S / dt | 50 | V/ns |
| Low-Side and Logic Fixed Supply Voltage | V _{CC} | -0.3 to +24 | V |
| Low-Side Output Voltage | V _{LO} | -0.3 to V _{CC} +0.3 | V |
| Logic Input Voltage (HIN and LIN) | V _{IN} | -0.3 to V _{CC} +0.3 | V |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|------------------|-------------|------|
| Power Dissipation Linear Derating Factor (Note 5) | P _D | 0.625 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{θJA} | 200 | °C/W |
| Thermal Resistance, Junction to Case (Note 5) | R _{θJC} | 45 | °C/W |
| Operating Temperature | TJ | +150 | - °C |
| Storage Temperature Range | T _{STG} | -55 to +150 | C |

Recommended Operating Conditions

| Parameter | Symbol | Min | Max | Unit |
|--|-----------------|--------------------|--------------------|------|
| High-Side Floating Supply Absolute Voltage | V _B | V _S +10 | V _S +20 | V |
| High-Side Floating Supply Offset Voltage | Vs | (Note 6) | 600 | V |
| High-Side Floating Output Voltage | V _{HO} | Vs | V _B | V |
| Low-Side Fixed Supply Voltage | Vcc | 10 | 20 | V |
| Low-Side Output Voltage | V_{LO} | 0 | Vcc | V |
| Logic Input Voltage (HIN and LIN) | V _{IN} | 0 | 5 | V |
| Ambient Temperature | T _A | -40 | +125 | °C |

Notes:

- 5. When mounted on a standard JEDEC 2-layer FR-4 board.
- 6. Logic operation for Vs of -5V to +600V.



DC Electrical Characteristics (V_{BIAS} (V_{CC}, V_{BS}) = 15V, @T_A = +25°C, unless otherwise specified.) (Note 7)

| Parameter | Symbol | Min | Тур | Max | Unit | Condition |
|---|---------------------|-----|-----|-------|------|---------------------------------|
| Logic "1" Input Voltage (Note 8) | V _{IH} | 2.5 | _ | _ | V | V _{CC} = 10V to 20V |
| Logic "0" Input Voltage (Note 8) | V_{IL} | _ | _ | 0.8 | V | $V_{CC} = 10V$ to $20V$ |
| High Level Output Voltage, V _{BIAS} - V _O | V _{OH} | _ | _ | 0.1 | V | $I_O = 0mA$ |
| Low Level Output Voltage, VO | V_{OL} | _ | _ | 0.035 | V | $I_O = 0mA$ |
| Offset Supply Leakage Current | I _{LK} | _ | _ | 50 | μΑ | $V_B = V_S = 600V$ |
| Quiescent V _{BS} Supply Current | I _{BSQ} | _ | 45 | 80 | μΑ | V _{IN} = 0V or 5V |
| Quiescent V _{CC} Supply Current | Iccq | _ | 75 | 200 | μΑ | V _{IN} = 0V or 5V |
| Logic "1" Input Bias Current | I _{IN+} | _ | 25 | 50 | μΑ | $V_{IN} = 5V$ |
| Logic "0" Input Bias Current | I _{IN-} | _ | 1.0 | 2.0 | μΑ | $V_{IN} = 0V$ |
| V _{BS} Supply Undervoltage Positive Going Threshold | V_{BSUV+} | 7.6 | 8.4 | 9.8 | V | _ |
| V _{BS} Supply Undervoltage Negative Going Threshold | V _{BSUV} - | 6.9 | 7.8 | 9.0 | V | _ |
| V _{CC} Supply Undervoltage Positive Going Threshold | V _{CCUV+} | 7.6 | 8.4 | 9.8 | V | _ |
| V _{CC} Supply Undervoltage Negative Going Threshold | V _{CCUV} - | 6.9 | 7.8 | 9.0 | V | _ |
| \\ and\\ Hadamakana Huatana'a | V _{CCUVH} | _ | 0.6 | _ | V | _ |
| V _{CC} and V _{BS} Undervoltage Hysteresis | V _{BSUVH} | _ | 0.6 | _ | V | _ |
| Output High Short Circuit Pulsed Current | I _{O+} | 3.5 | 4.5 | _ | Α | V _O = 0V, PW ≤ 10ms |
| Output Low Short Circuit Pulsed Current | I _{O-} | 3.5 | 4.5 | _ | Α | V _O = 15V, PW ≤ 10ms |

Notes:

AC Electrical Characteristics (V_{BIAS} (V_{CC} , V_{BS}) = 15V, C_L = 1000pF, @ T_A = +25°C, unless otherwise specified.)

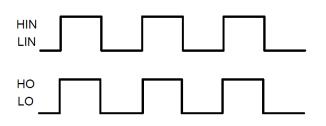
| Parameter | Symbol | Min | Тур | Max | Unit | Condition |
|-------------------------------------|------------------|-----|-----|-----|------|------------|
| Turn-On Propagation Delay | toN | _ | 140 | 200 | ns | $V_S = 0V$ |
| Turn-Off Propagation Delay | t _{OFF} | _ | 140 | 200 | ns | $V_S = 0V$ |
| Delay Matching, HO & LO Turn On/Off | t _{DM} | _ | _ | 50 | ns | _ |
| Turn-On Rise Time | t _R | _ | 25 | 50 | ns | $V_S = 0V$ |
| Turn-Off Fall Time | t _F | _ | 20 | 45 | ns | $V_S = 0V$ |

^{7.} The V_{IN} and I_{IN} parameters are applicable to the two logic pins; HIN and LIN. The V_O and I_O parameters are applicable to the respective output pins: HO and LO.

^{8.} For optimal operation, it is recommended that the input pulses (HIN and LIN) should have a minimum amplitude of 2.5V with a minimum pulse width of 280ns.



Timing Waveforms



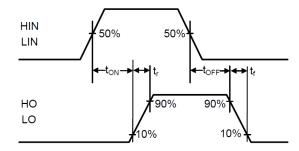


Figure 1. Input / Output Timing Diagram

Figure 2. Switching Time Waveform Definitions

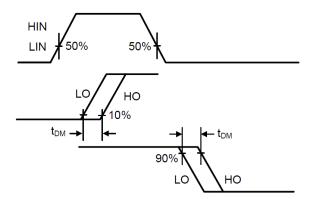


Figure 3. Delay Matching Waveform Definitions



Typical Performance Characteristics (Vcc=15V, @TA = +25°C, unless otherwise specified.)

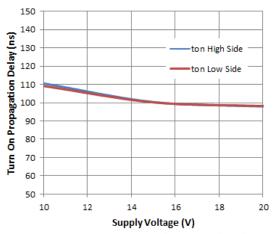


Figure 4. Turn-on Propagation Delay vs. Supply Voltage

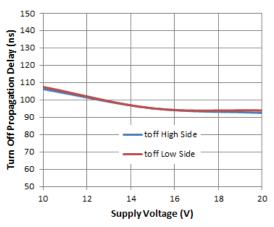


Figure 6. Turn-off Propagation Delay vs. Supply Voltage

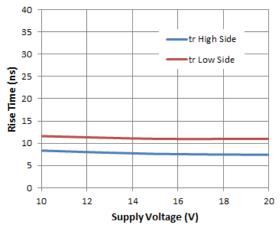


Figure 8. Rise Time vs. Supply Voltage

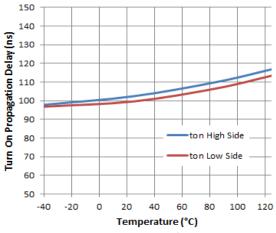


Figure 5. Turn-on Propagation Delay vs. Temperature

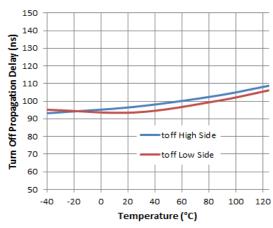


Figure 7. Turn-off Propagation Delay vs. Temperature

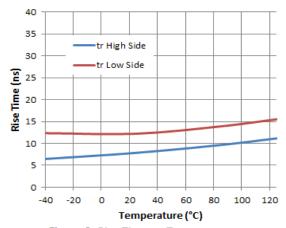


Figure 9. Rise Time vs. Temperature



Typical Performance Characteristics (continued) (@T_A = +25°C, unless otherwise specified.)

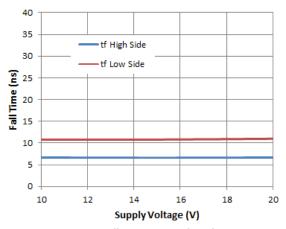


Figure 10. Fall Time vs. Supply Voltage

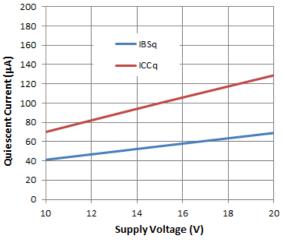


Figure 12. Quiescent Current vs. Supply Voltage

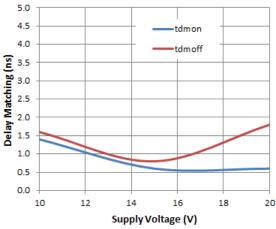


Figure 14. Delay Matching vs. Supply Voltage

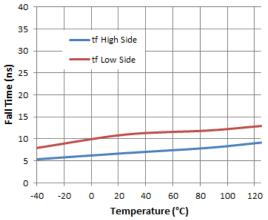


Figure 11. Fall Time vs. Temperature

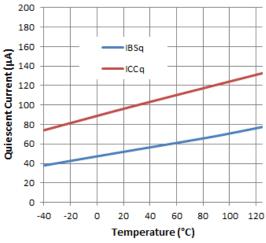


Figure 13. Quiescent Current vs. Temperature

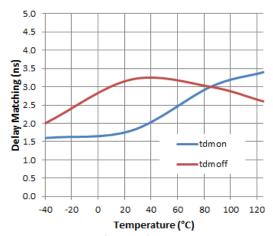


Figure 15. Delay Matching vs. Temperature



Typical Performance Characteristics (continued) (@T_A = +25°C, unless otherwise specified.)

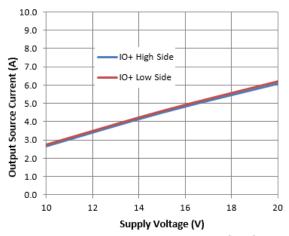


Figure 16. Output Source Current vs. Supply Voltage

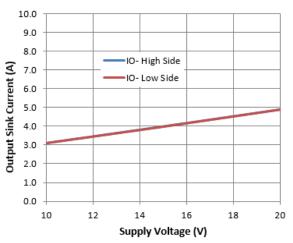


Figure 18. Output Sink Current vs. Supply Voltage

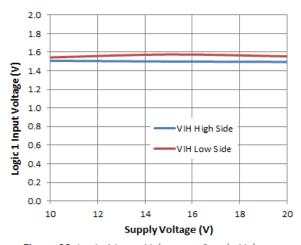


Figure 20. Logic 1 Input Voltage vs. Supply Voltage

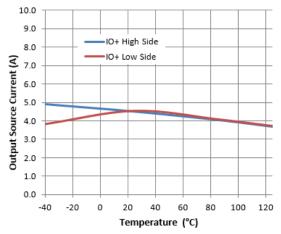


Figure 17. Output Source Current vs. Temperature

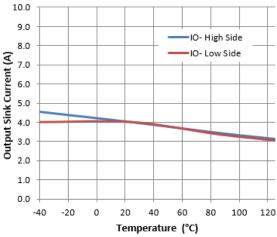


Figure 19. Output Sink Current vs. Temperature

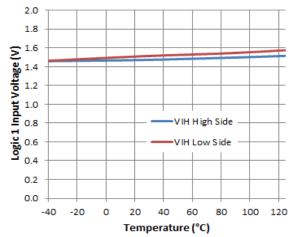


Figure 21. Logic 1 Input Voltage vs. Temperature



Typical Performance Characteristics (continued) (@T_A = +25°C, unless otherwise specified.)

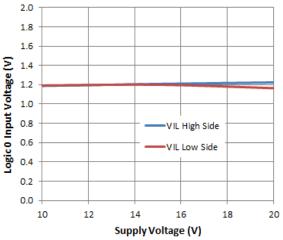


Figure 22. Logic O Input Voltage vs. Supply Voltage

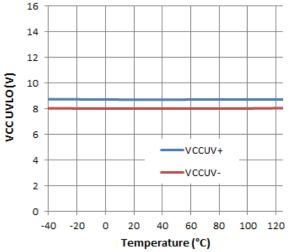


Figure 24. VCC UVLO vs. Temperature

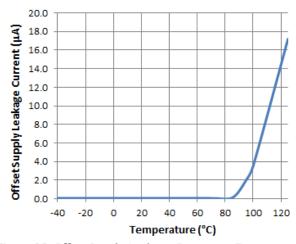


Figure 26. Offset Supply Leakage Current vs. Temperature

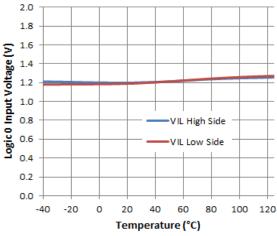


Figure 23. Logic 0 Input Voltage vs. Temperature

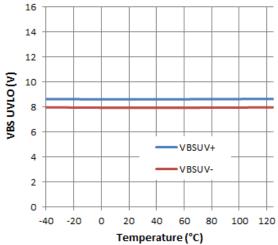


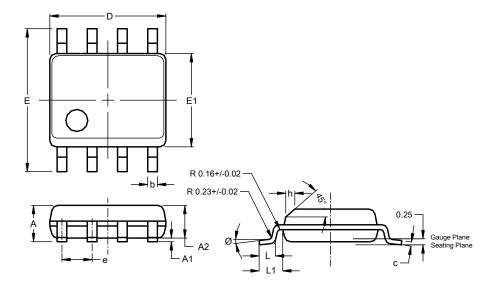
Figure 25. VBS UVLO vs. Temperature



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8 (Type TH)

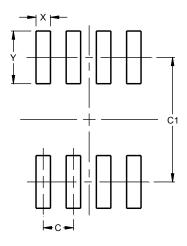


| SO-8 (Type TH) | | | | | | |
|----------------------|-------|-------|------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 1.35 | 1.75 | _ | | | |
| A1 | 0.10 | 0.25 | _ | | | |
| A2 | _ | _ | 1.45 | | | |
| b | 0.35 | 0.51 | _ | | | |
| С | 0.190 | 0.248 | _ | | | |
| D | 4.80 | 5.00 | 4.90 | | | |
| Е | 5.80 | 6.20 | 6.00 | | | |
| E1 | 3.80 | 4.00 | 3.90 | | | |
| е | _ | _ | 1.27 | | | |
| h | 0.25 | 0.50 | 1 | | | |
| L | 0.41 | 1.27 | - | | | |
| L1 | _ | _ | 1.04 | | | |
| Ø | 0° | 8° | _ | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8 (Type TH)



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 1.27 |
| C1 | 5.20 |
| Х | 0.60 |
| Y | 2.20 |

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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